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HIGH ISOLATION SPDT NON-REFLECTIVE SWITCH, DC - 4 GHz

Typical Applications

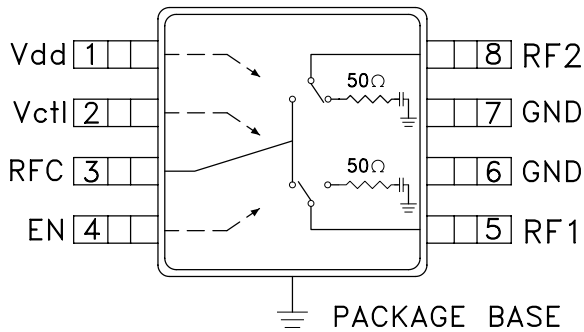
The HMC349AMS8G / 349AMS8GE is ideal for:

- Basestation Infrastructure
- MMDS & 3.5 GHz WLL
- CATV/CMTS
- Test Instrumentation

Features

- High Isolation: 70 dB @ 1 GHz
57 dB @ 2 GHz
- Single Positive Control: 0/+5V
- +52 dBm Input IP3
- Non-Reflective Design
- All Off State
- Ultra Small MS8G SMT Package: 14.8 mm²

Functional Diagram



General Description

The HMC349AMS8G & HMC349AMS8GE are high isolation non-reflective DC to 4 GHz GaAs MESFET SPDT switches in low cost 8 lead MSOP8G surface mount packages with exposed ground paddles. The switch is ideal for cellular/PCS/3G basestation applications yielding 50 to 60 dB isolation, low 0.8 dB insertion loss and +52 dBm input IP3. Power handling is excellent up through the 3.5 GHz WLL band with the switch offering a P1dB compression point of +34 dBm. On-chip circuitry allows a single positive voltage control of 0/+5 Volts at very low DC currents. An enable input (EN) set to logic high will put the switch in an "all off" state.

Electrical Specifications, $T_A = +25^\circ C$, $V_{ctl} = 0/+5 V_{dc}$, $V_{dd} = +5 V_{dc}$, 50 Ohm System

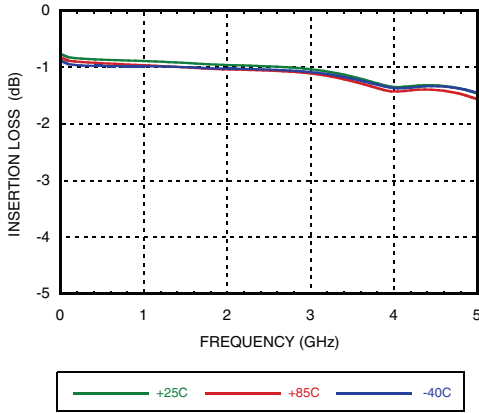
Parameter	Frequency	Min.	Typ.	Max.	Units
Insertion Loss	DC - 1.0 GHz		0.8	1.1	dB
	DC - 2.0 GHz		0.9	1.2	dB
	DC - 3.0 GHz		1.2	1.5	dB
	DC - 4.0 GHz		1.8	2.1	dB
Isolation (RFC to RF1/RF2)	DC - 1.0 GHz	60	70		dB
	DC - 2.0 GHz	54	57		dB
	DC - 3.0 GHz	45	50		dB
	DC - 4.0 GHz	42	47		dB
Return Loss (On State)	DC - 1.0 GHz		23		dB
	DC - 2.0 GHz		22		dB
	DC - 3.0 GHz		20		dB
	DC - 4.0 GHz		18		dB
Return Loss (Off State)	0.5 - 2.0 GHz		22		dB
	0.5 - 3.0 GHz		17		dB
	0.5 - 4.0 GHz		14		dB
Input Power for 1 dB Compression	0.25 - 4.0 GHz	30	34		dBm
Input Third Order Intercept (Two-Tone Input Power = +10 dBm Each Tone)	0.25 - 1.0 GHz		53		dBm
	1.0 - 2.0 GHz		54		dBm
	2.0 - 3.0 GHz		53		dBm
	3.0 - 4.0 GHz		52		dBm
Switching Speed	DC - 4.0 GHz				
		tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)		60 160	ns ns

For price, delivery and to place orders: Hittite Microwave Corporation, 2 Elizabeth Drive, Chelmsford, MA 01824

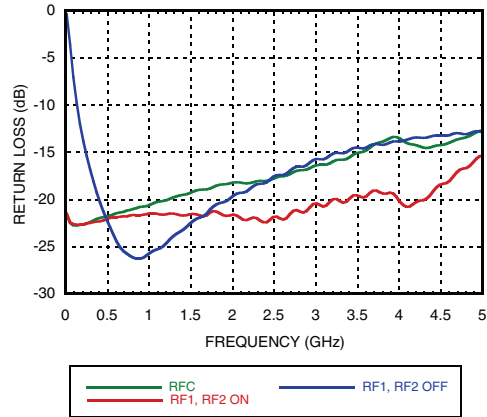
Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

Application Support: Phone: 978-250-3343 or apps@hittite.com

Insertion Loss

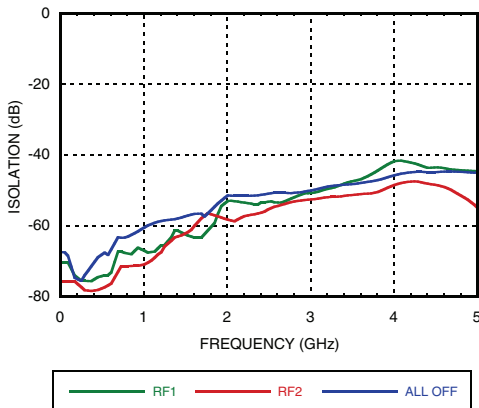


Return Loss

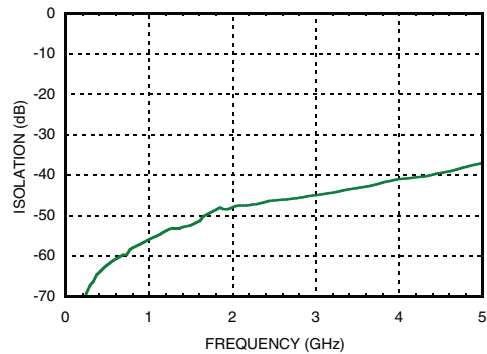


Note: RFC is reflective in "all off" state.

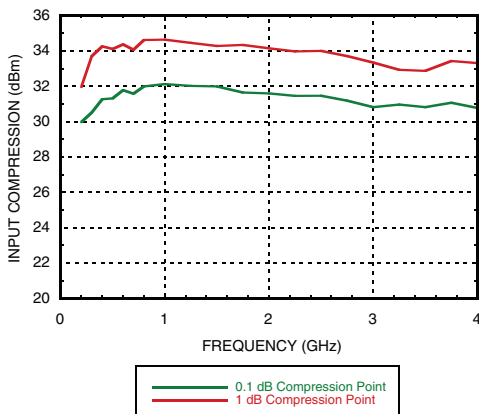
Isolation Between Ports RFC and RF1 / RF2



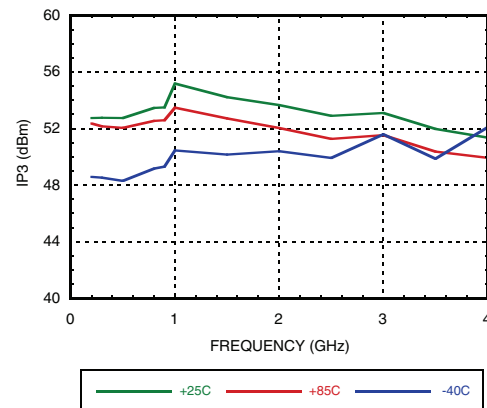
Isolation Between Ports RF1 and RF2



0.1 and 1 dB Input Compression Point



Input Third Order Intercept Point




Absolute Maximum Ratings

RF Input Power (Vctl = 0V/+5V) (0.25 - 4 GHz)	
Through Path	33.6 dBm
Termination Path	26.5 dBm
Supply Voltage Range (Vdd)	+7 Vdc
Control Voltage Range (Vctl)	-1V to Vdd +1V
Hot Switch Power Level (Vdd = +5V)	+30 dBm
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 17.6 mW/°C for through path, 8.6 mW/°C for termination path above 85 °C)	
Through Path	0.969 W
Termination Path	0.451 W
Thermal Resistance	
Through Path	67.1 °C/W
Termination Path	144.2 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

Bias Voltage & Current

Vdd Range = +5.0 Vdc ± 10%		
Vdd (Vdc)	Idd (Typ.) (mA)	Idd (Max.) (mA)
+5.0	1.2	3.5

TTL/CMOS Control Voltages

State	Bias Condition
Low	0 to +0.8 Vdc @ <1 µA Typical
High	+2.0 to +5.0 Vdc @ 40 µA Typical

Truth Table

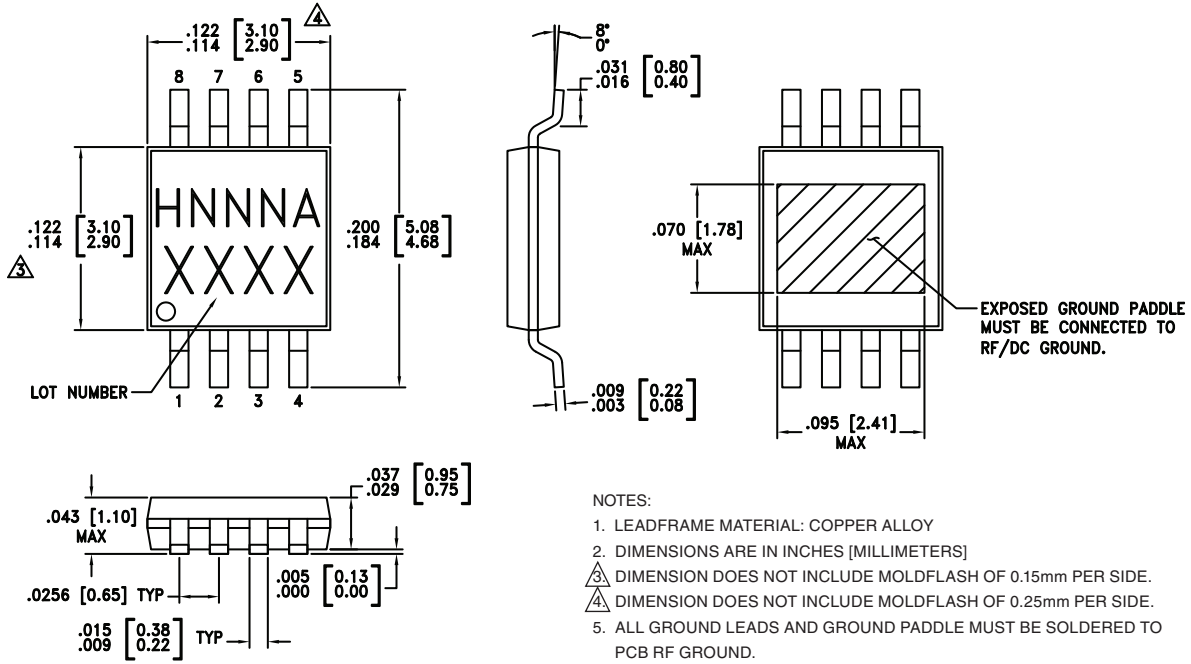
Control Input		Signal Path State	
Vctl	EN	RFC - RF1	RFC - RF2
Low	Low	OFF	ON
High	Low	ON	OFF
Low	High	OFF	OFF
High	High	OFF	OFF

Note: DC blocking capacitors are required at ports RFC, RF1 and RF2. Their value will determine the lowest transmission frequency.



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC349AMS8G	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H349A XXXX
HMC349AMS8GE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H349A XXXX

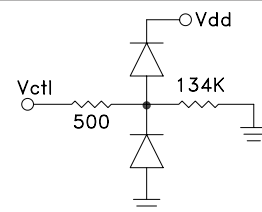
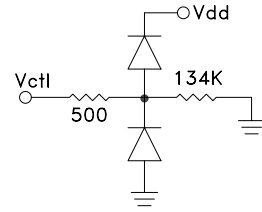

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

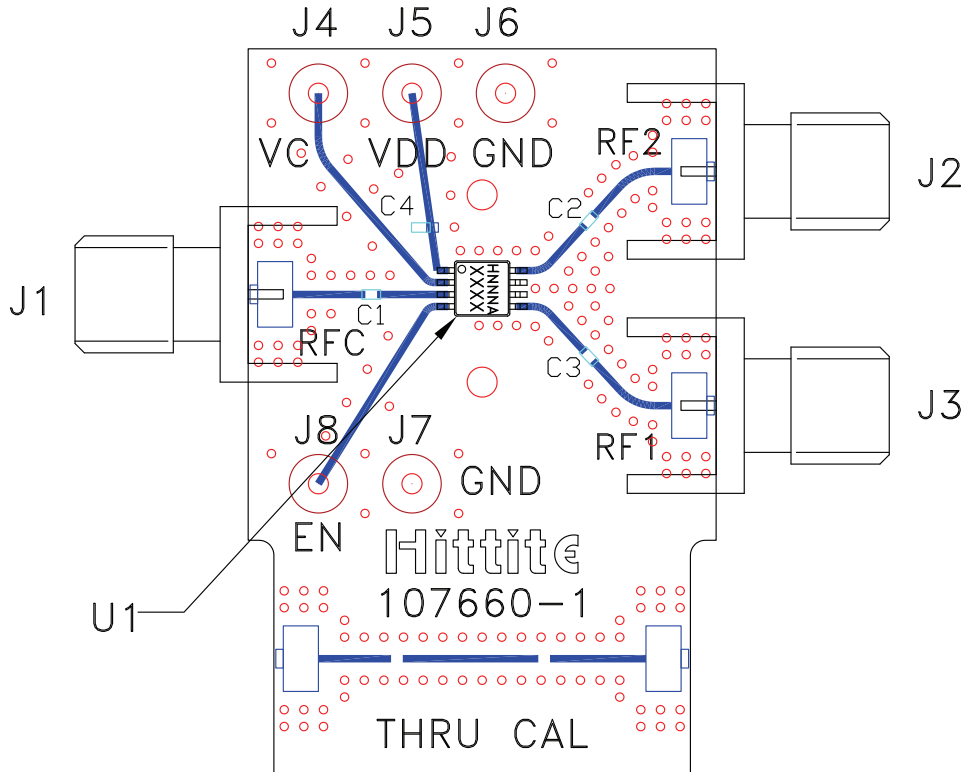
[3] 4-Digit lot number XXXX



Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	Vdd	Supply Voltage.	
2	Vctl	Control input. See truth and control voltage tables.	
3, 5, 8	RFC, RF1, RF2	These pins are DC coupled and matched to 50 Ohms. Blocking capacitors are required.	
4	EN	Enable. See truth and control voltage tables.	
6, 7	GND	Package bottom must also be connected to PCB RF ground.	

Evaluation PCB



List of Materials for Evaluation PCB 107662 - HMC349AMS8G [1]

Item	Description
J1 - J3	PCB Mount SMA RF Connector
J4 - J8	DC Pin
C1 - C3	100 pF Capacitor, 0402 Pkg.
U1	HMC349AMS8G / 349AMS8GE SPDT Switch
PCB [2]	107660 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 Ohm impedance and the package ground leads and backside ground slug should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.



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Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.